



1. Features

- (1) 3.3V~5V supply voltage
- (2) Low power consumption
- (3) High speed: 15MBd(typical)
- (4) V_{OM}=1000V, and the lowest common mode isolation. (MOS technology)
- (5) -40 °C ~ +110 °C temperature of AC and DC performance.
- (6) ~~RoHS approval~~ (No.E323844)
- ~~RoHS approval (No.4001873)~~
- ~~RoHS approval (IECQ-C9001234)~~
- (7) In compliance with RoHS, REACH standards



DIVIDE THE INPUT SIGNAL FROM THE FIELD STRANDING CIRCUIT

and high-speed optical detector. This design provides good ac and dc isolation

between the input and output ends of the photoelectric coupling

characteristic of the photodetector is a collector-open circuit schottky clamping

function. The clamping voltage is about 1.2V at 10mA DC3.3V.

The phototransistor can operate over a wide range, ranging from -40 to +110 °C.

2. AV/D, D/A converted digital signal isolation

- 3. eliminate noise from the ground loop
- 4. switching power supply

3. INTERFACE OF MICROPROCESSOR SYSTEM, COMPUTER AND PERIPHERAL EQUIPMENT

4. ELECTRICAL DIAGRAM



5.1 capacitor T bypass capacitor needs to be connected to ground between the two terminals

5. Absolute Maximum Ratings ($T_a=25^{\circ}\text{C}$)²¹

| Parameter | | Symbol | Rated Value | Unit |
|-----------|------------------------------------|----------------|----------------------|------|
| Input | Average Forward Input Current | I _F | 20 | mA |
| | Reverse Input Voltage | V _R | 5 | V |
| | Power Dissipation | P _r | 40 | mW |
| | Enable Input Voltage | V _E | V _{CC} +0.5 | V |
| | Enable Input current | I _E | 5 | mA |
| Output | Output Collector Current | I _O | 50 | mA |
| | Output Collector Voltage | V _O | 7 | V |
| | Output Collector Power Dissipation | P _O | 85 | mW |

